



BC847AT, BT, CT

NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

Epitaxial Die Construction

Complementary PNP Type Available (BC857AT,BT,CT)

Ultra-Small Surface Mount Package

Lead Free/RoHS Compliant (Note 2)

Mechanical Data

Case: SOT-523

Case Material - Molded Plastic. UL Flammability

Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminals: Solderable per MIL-STD-202, Method 208

Lead Free Plating (Matte Tin Finish annealed over Alloy 42

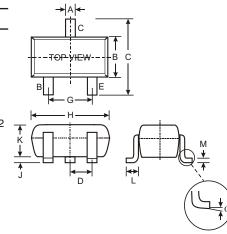
leadframe).

Terminal Connections: See Diagram

Marking Code: See Table Below & Diagram

on Page 2

Ordering Information: See Page 2 Date Code Information: See Page 2 Weight: 0.002 grams (approximate)



	SOT	-523								
Dim	Min	Max	Тур							
Α	0.15	0.30	0.22							
В	0.75	0.85	0.80							
С	1.45	1.75	1.60							
D			0.50							
G	0.90	1.10	1.00							
Н	1.50	1.70	1.60							
J	0.00	0.10	0.05							
K	0.60	0.80	0.75							
L	0.10	0.30	0.22							
М	0.10	0.20	0.12							
N	0.45	0.65	0.50							
	0	8								
AII C	All Dimensions in mm									

Туре	Marking
BC847AT	1E
BC847BT	1F
BC847CT	1M

@ T_A = 25°C unless otherwise specified **Maximum Ratings**

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	Ic	100	mA
Power Dissipation (Note 1)	Pd	150	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{JA}	833	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
DC Current Gain (Note 3)	Current Gain A B C Current Gain A B C	h _{FE}	 110 200 420	150 270 — 290 520	 220 450 800	_	V _{CE} = 5.0V, I _C = 2.0mA
Collector-Emitter Saturation Voltage	(Note 3)	V _{CE(SAT)}		_	250 600	mV	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA
Base-Emitter Saturation Voltage	(Note 3)	V _{BE(SAT)}	_	700 900	_	mV	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA
Base-Emitter Voltage	(Note 3)	V _{BE}	580 —	660 —	700 770	mV	V _{CE} = 5.0V, I _C = 2.0mA V _{CE} =5.0V, I _C = 10mA
Collector-Emitter Cutoff Current	(Note 3)	I _{CBO}	_	_	15 5.0	nΑ μΑ	V _{CB} = 30V V _{CB} = 30V, T _A = 150°C
Gain Bandwidth Product		f⊤	100		_	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz
Output Capacitance		C _{OBO}	_	_	4.5	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure	BC847BT BC847CT	NF	_		10 4.0	dB	V _{CE} = 5V, R _S = 2.0k f = 1.0kHz, BW = 200Hz

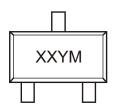
Notes: 3. Short duration pulse test used to minimize self-heating effect.

Ordering Information (Note 4)

Device	Packaging	Shipping
BC847AT-7-F	SOT-523	3000/Tape & Reel
BC847BT-7-F	SOT-523	3000/Tape & Reel
BC847CT-7-F	SOT-523	3000/Tape & Reel

4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information



XX = Product Type Marking Code (See Page 1), e.g. 1E = BC847AT

YM = Date Code Marking

Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



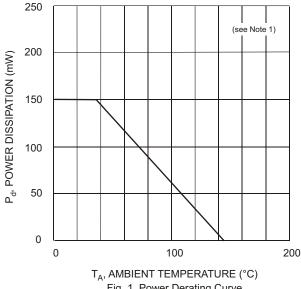
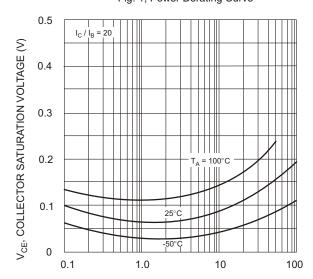
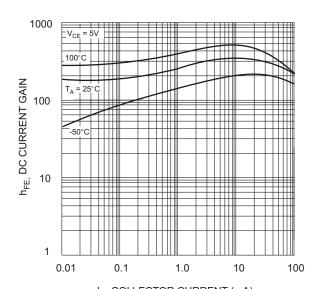


Fig. 1, Power Derating Curve



I_C, COLLECTOR CURRENT (mA) Fig. 3, Collector Saturation Voltage vs Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 2, DC Current Gain vs Collector Current

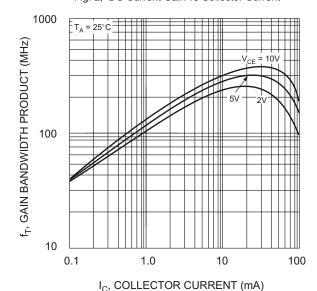


Fig. 4, Gain Bandwidth Product vs Collector Current

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